A Novel Phase Transition in Conductive Molecular Crystals based on Metal Bis-diselenoalkene Complexes: $[TMTSF]_2[M\{Se_2C_2(CF_3)_2\}_2]$; M = Ni, Pt; TMTSF = tetramethyltetraselenafulvalene

William B. Heuer and Brian M. Hoffman*

Department of Chemistry, Northwestern University, Evanston, Illinois 60201, U.S.A.

Single crystals of [TMTSF]₂[M{Se₂C₂(CF₃)₂}₂] (TMTSF = tetramethyltetraselenafulvalene; M = Ni, Pt) have room-temperature conductivities of 20—65 Ω^{-1} cm⁻¹ and upon cooling undergo an unprecedented phase transition in which the low temperature phase shows enhanced electrical conductivity: M = Ni, $T_c = ca$. 275 K; M = Pt, $T_c = ca$. 245 K.

Planar metal bis-dithioalkene complexes are attractive precursors for molecular metals because of their delocalized elec tronic structure and range of stable oxidation states. 1 Further more, close intermolecular contacts mediated by the chalcogen atoms of these complexes can produce conductive crystals that exhibit quasi-2- or 3-dimensional character,² as is found in the organic superconductors.³ In principle, the selenium analogues of such complexes (metal bis-diselenoalkenes) would be better suited for the formation of extended, multi-dimensional molecular networks because of the increased Van der Waals radius and greater polarizability of selenium. However, relatively few metal bis-diselenoalkene complexes have been reported,4,5 and only one family of conductive compounds has been briefly described. We report here the synthesis and preliminary physical characterization of new molecular conductors that are based on metal bisdiselenoalkene complexes and that exhibit an unprecedented type of phase transition near room temperature.

Salts of the monoanions $[M\{Se_2C_2(CF_3)_2\}_2]^-$ (M = Ni, Pt) were prepared⁶ by the reaction of bis(perfluoromethyl)ethylene diselenate⁷ with low valent phosphine–metal complexes under conditions similar to those employed⁸ for the prepara-

 $\begin{bmatrix} F_3C & Se & Se & CF_3 \\ F_3C & Se & Se & CF_3 \end{bmatrix}$ (1) M = Ni (2) M = Pt

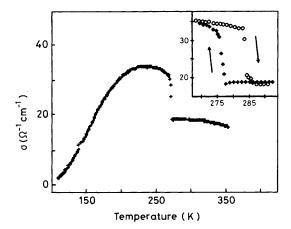


Figure 1. Needle-axis conductivity of $[TMTSF]_2[Ni\{Se_2C_2(CF_3)_2\}_2]$ single crystal (cooling). Inset shows hysteresis upon temperature cycling through phase transition.

tion of the analogous sulphur species. Flexible black needles of formula [TMTSF]2[M{Se}_2C_2(CF_3)_2)_2], [TMTSF = tetramethyltetraselenafulvalene; M = Ni, (1), M = Pt, (2)] were crystallized at a platinum wire anode by constant current (1—2 μA) electrolysis of a 1,1,2-trichloroethane solution containing TMTSF (4 \times 10⁻³ M) and the corresponding monoanionic metal complex (2 \times 10⁻³ M). The stoicheiometry of the products was determined by elemental analysis.

Four-probe D.C. conductivity studies show that (1) and (2) conduct well along the needle axis (σ_{RT} ca. 20 and 65 Ω^{-1} cm⁻¹, respectively) with weakly metallic temperature dependence near room temperature. Upon cooling single crystals of (1) through T_c ca. 275 K, an abrupt *increase* in conductivity is observed, followed by a broad plateau and activated behaviour below ca. 220 K (Figure 1). Slow warming back to room temperature reveals a pronounced hysteresis associated with the reverse transition (inset). The behaviour of the corresponding platinum compound (2) is qualitatively similar, except the transition upon cooling occurs at 245 K.

Polycrystalline samples of (2) have no detectable e.s.r. signal down to 77 K. At room temperature, similar samples of (1) show a single, broad ($\Delta H_{\rm p-p}=265~{\rm G}:1~{\rm G}=10^{-4}~{\rm T}$) e.s.r. signal at g=2.088. The temperature response of the peak-to-peak intensity of this signal (Figure 2) shows a break near $T_{\rm c}$. This is unaccompanied by any detectable anomaly in the integrated intensity, and instead appears to result from a subtle change in lineshape at the transition. Temperature cycling (inset) confirms that the hysteresis seen in the conductivity data is an intrinsic property of these materials.

Preliminary results of X-ray diffraction studies indicate that the transition in conductivity correlates with a change in

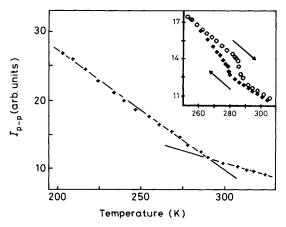


Figure 2. Temperature dependence of peak-to-peak e.s.r. intensity for polycrystalline $[TMTSF]_2[Ni\{Se_2C_2(CF_3)_2\}_2]$. Inset shows that the change in slope is accompanied by a small change in value, and displays the hysteresis upon temperature cycling.

structure.⁹ By analogy to studies on the related, nonconducting metal dithioalkene salts of the type $[TTF][M\{S_2C_2(CF_3)_2\}_2]$ (TTF = tetrathiafulvalene; M = Cu, Au, Pt), 10 the change may be a first-order phase transition involving the ordering of rotationally disordered - CF_3 substituents.

To our knowledge, compounds (1) and (2) provide the first example of a structural transition in which the low temperature state is more conductive than the high temperature state. Indeed, the superconducting state provides the only other case of a transition to a low temperature state of higher conductivity.

This work was supported by the Solid State Chemistry Program of the National Science Foundation and by the Northwestern University Materials Research Center under the NSF-MRL program. We acknowledge Johnson, Matthey Inc. for the loan of platinum salts.

Received, 14th October 1985; Com. 1472

References

L. Alcacer and H. Novais, in 'Extended Linear Chain Compounds,' Vol. 3, ed. J. S. Miller, Plenum Press, New York, 1983, pp. 319—351.

- 2 A. Kobayashi, Y. Sasaki, H. Kobayashi, A. E. Underhill, and M. M. Ahmad, J. Chem. Soc., Chem. Commun., 1982, 390; R. Kato, T. Mori, A. Kobayashi, Y. Sasaki, and H. Kobayashi, Chem. Lett., 1984, 1; M. Bousseau, L. Valade, M.-F. Bruniquel, P. Cassoux, M. Garbauskas, L. Interrante, and J. Kasper, Nouv. J. Chim., 1984, 3; L. Valade, J.-P. Legros, M. Bousseau, P. Cassoux, M. Garbauskas, and L. V. Interrante, J. Chem. Soc., Dalton Trans., 1985, 783; R. Kato, H. Kobayashi, A. Kobayashi, and Y. Sasaki, Chem. Lett., 1985, 131; H. Kobayashi, R. Kato, A. Kobayashi, and Y. Sasaki, ibid., 1985, 191; H. Kobayashi, R. Kato, A. Kobayashi, and Y. Sasaki, ibid., 1985, 1935.
- 3 G. Saito, T. Enoki, K. Toriumi, and H. Inokuchi, Solid State Commun., 1982, 42, 557; J. M. Williams, M. A. Beno, J. C. Sullivan, L. M. Banovetz, J. M. Braan, G. S. Blackman, C. P. Carlson, D. L. Greer, and D. M. Loesing, J. Am. Chem. Soc., 1983, 105, 643.
- 4 A. Davison and E. T. Shawl, *Inorg. Chem.*, 1970, 9, 1820; D. J. Sandman, J. C. Stark, L. A. Acampora, L. A. Samuelson, and G. W. Allen, *Mol. Cryst. Liq. Cryst.*, 1984, 107, 1; F. Wudl, E. T. Zellers, and S. D. Cox, *Inorg. Chem.*, 1985, 24, 2864.
- G. C. Papavassiliou, Mol. Cryst. Liq. Cryst., 1982, 86, 159; Z. Naturforsch. Teil B, 1982, 37, 825.
- 6 W. B. Heuer and B. M. Hoffman, manuscript in preparation.
- 7 A. Davison and E. T. Shawl, Chem. Commun., 1967, 670.
- 8 A. Davison, D. V. Howe, and E. T. Shawl, *Inorg. Chem.*, 1967, 6, 458.
- 9 W. B. Heuer, J. A. Ibers, and B. M. Hoffman, work in progress.
- 10 J. A. Ibers, L. J. Pace, J. Martinsen, and B. M. Hoffman, Struct. Bonding (Berlin), 1982, 50, 1, and refs. therein.